

Description

The DFB-1310-C5-2-2.5-xx-x-x-x series of Multi-Quantum Well (MQW) Distributed Feedback (DFB) lasers have been designed specifically to satisfy the requirements of ITU-G.959 S16.1 and L16.1. The devices feature high output power and wide operating temperature range.

Their uncooled, hermetically sealed, coaxial fiberpigtailed packages are a cost-effective means of providing a high-speed light source for intermediatereach and long-reach applications.

Features

- Advanced Multiple Quantum Well (MQW)
 Distributed Feedback (DFB) Laser Design
- ☐ High-speed up to 2.5 Gbps
- □ Engineered Specifically for SONET S16.1 and L16.1
- □ Low-Cost Uncooled Laser Technology
- □ 1-meter SMF-28 Fiber Pigtail
- □ 5.6-mm TO-style package with SMF pigtail

Applications

- □ SONET S16.1 2.5 Gbps transmitter
- □ SONET L16.1 2.5 Gbps transmitter
- ☐ Intermediate and long-distance fiber transmitter





DFB-1310-C5-2-2.5-xx-x-x-x

Absolute Maximum Ratings

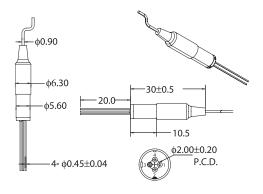
Parameter	Symbol	Condition	Min	Max	Unit
Operating Case Temperature	T _c	$I=I_{op}$	-20	85	°C
Storage Temperature	T _{sta}		-40	100	°C
Laser Forward Current	\mathbf{I}_{f}			120	mA
Laser Reverse Bias	V_r			2	V
Photodiode Reverse Bias	V _{rnd}			10	V

Electrical/Optical Characteristics

Parameters are over		

Parameters are over operating temperature range unless otherwise noted.							
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions	
Operating Temp.	T	-20		85*	°C		
Optical Output Power	P_o	2.0	-		mW	CW	
Threshold Current	I_{th}		12	18	mA	T=25 °C	
			35	50		T=85 °C	
Forward Voltage	V_F		1.1	1.6	V	P _o =2.0 mW	
Operating Current	I_{op}		22	35	mA	P _o =2.0 mW, T=25	
			60	75		°C	
						P_0 =2.0 mW, T=85	
						С	
Center Wavelength	λ_{c}	1270	1310	1350	nm	P _o =2.0 mW, CW	
Spectral Width (-20 dB)	Δλ		0.1	1.0	nm	P _o =2.0 mW	
Wavelength Temp.	Δλ /ΔΤ		0.09	0.1	nm/°C		
Coefficient							
Side-mode Suppression	SMSR	30	40		dB	P _o =2.0 mW	
Ratio							
Rise/Fall Times	t_R , t_F			0.1	ns	Ppeak=2.0 mW,	
						20% to 80%	
Relaxation Oscillation	f _R		4.5		GHz	P _o =2.0 mW	
Frequency							
Monitor Current	I_{mon}	25		375	μ A/mW	$V_{rpd}=5 V$	
Monitor Dark Current	I_D		1	200	nA	$V_{rpd}=5 V$	
Relative Intensity Noise	RIN		-140	-130	dB/Hz	P _o =2.0 mW, 30 dB	
-						isolation	
Tracking Error	γ	-1		1	dB	I_{mon} =const, γ =10	
						log (P _o /2.0) [dB]	
Optical Isolation**	ISO	30			dB		

Dimensions (in mm)

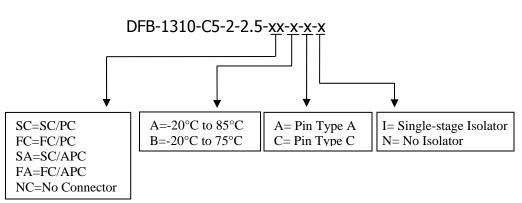


Pin Assignment Type A PD Cathode PD Anode LD Anode,PD Cathode LD Anode, GRD GRD

LD cathode

LD cathode

Ordering Options



^{**}See Ordering Options for available temperature ranges

**Optical Isolation is only applicable to devices that include the optical isolator option



DFB-1310-C5-2-2.5-xx-x-x-x

Safety Information

All version of this laser are Class 1M laser products per IEC* 60825-1:2001. Users should observe safety precautions such as those recommended by ANSI** Z136.1-2000, ANSI Z36.2-1997 and IEC 60825-1:2001.

This product does not conform to 21 CFR 1040.10 and 1040.11. Consequently, this laser module is only intended for use as a component by manufacturers of electronic products and equipment.

Wavelength = 1.3 µm Maximum Power = 75 mW Single-mode fiber pigtail Fiber Numerical Aperture = 0.14

Labeling is not affixed to the laser module due to size constraints; rather, labeling is placed on the outside of the shipping box.

This product is not shipped with a power supply.

Caution: use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.



*IEC is a registered trademark of the International Electrotechnical Commission

^{**}ANSI is a registered trademark of the American National Standards Institute